Docket No.

240438US2

IN RE APPLICATION OF:

Hirokazu SAYAN

SERIAL NO: 10/620,379

FILED:

July 17, 2003

FOR:

SEMICONDUCTOR DEVICE INCLUDING GATE ELECTRODE FOR APPLYING TENSILE STRESS TO

SILICON SUBSTRATE, AND METHOD OF MANUFACTURING THE SAME

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

## SIR:

Transmitted herewith is an amendment in the above-identified application.

- No additional fee is required
- ☐ Small entity status of this application under 37 C.F.R. §1.9 and §1.27 is claimed.
- ☐ Additional documents filed herewith:

The Fee has been calculated as shown below:

CLAIMS	CLAIMS REMAINING		HIGHEST NUMBER PREVIOUSLY PAID	NO. EXTRA CLAIMS		RATE		CALCULATIONS
TOTAL	6	MINUS	20	0	x	\$50	II	\$0.00
INDEPENDENT	1	MINUS	3	0	х	\$200	=	\$0.00
☐ MULTIPLE DEPENDENT CLAIR					+	\$360	=	\$0.00
TOTAL OF ABOVE CALCULATIONS							\$0.00	
☐ Reduction by 50% for filing by Small Entity							\$0.00	
		☐ Recordation of Assignment				\$40	=	\$0.00
		тс					AL	\$0.00

Ш	Α	check	in the	e amount	of	<u>\$0.00</u>	1S	attach	ied	l.
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- ☐ Credit card payment form is attached to cover the fees in the amount of \$0.00
- Please charge any additional Fees for the papers being filed herewith and for which no check or credit card payment is enclosed herewith, or credit any overpayment to deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.
- If these papers are not considered timely filed by the Patent and Trademark Office, then a petition is hereby made under 37 C.F.R. §1.136, and any additional fees required under 37 C.F.R. §1.136 for any necessary extension of time may be charged to Deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.

OBLON, SPIVAK, McCLELLAND, MAIER & NEUSTADT, P.C.

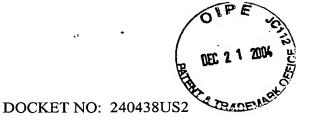
Registration No. 25,599

Customer Number

22850

Tel. (703) 413-3000 Fax. (703) 413-2220 (OSMMN 05/03)

Michael E. Monaco Registration No. 52,041



## IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

HIROKAZU SAYAMA, ET AL. : EXAMINER: NHU, DAVID

SERIAL NO: 10/620,379

FILED: JULY 17, 2003 : GROUP ART UNIT: 2818

FOR: SEMICONDUCTOR DEVICE INCLUDING GATE ELECTRODE FOR APPLYING TENSILE STRESS TO SILICON SUBSTRATE, AND METHOD OF MANUFACTURING THE SAME

## **AMENDMENT**

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated September 21, 2004, please amend the aboveidentified application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 5 of this paper.